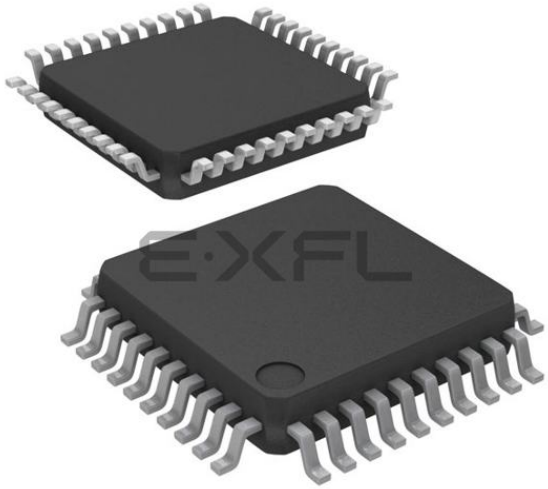

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	SIO, UART/USART
Peripherals	LED, POR, Voltage Detect, WDT
Number of I/O	22
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21114fp-u0

1. Overview

This MCU is built using the high-performance silicon gate CMOS process using a R8C/Tiny Series CPU core and is packaged in a 32-pin plastic molded LQFP. This MCU operates using sophisticated instructions featuring a high level of instruction efficiency. With 1M bytes of address space, it is capable of executing instructions at high speed.

1.1 Applications

Electric household appliance, office equipment, housing equipment (sensor, security), general industrial equipment, audio, etc.

1.3 Block Diagram

Figure 1.1 shows this MCU block diagram.

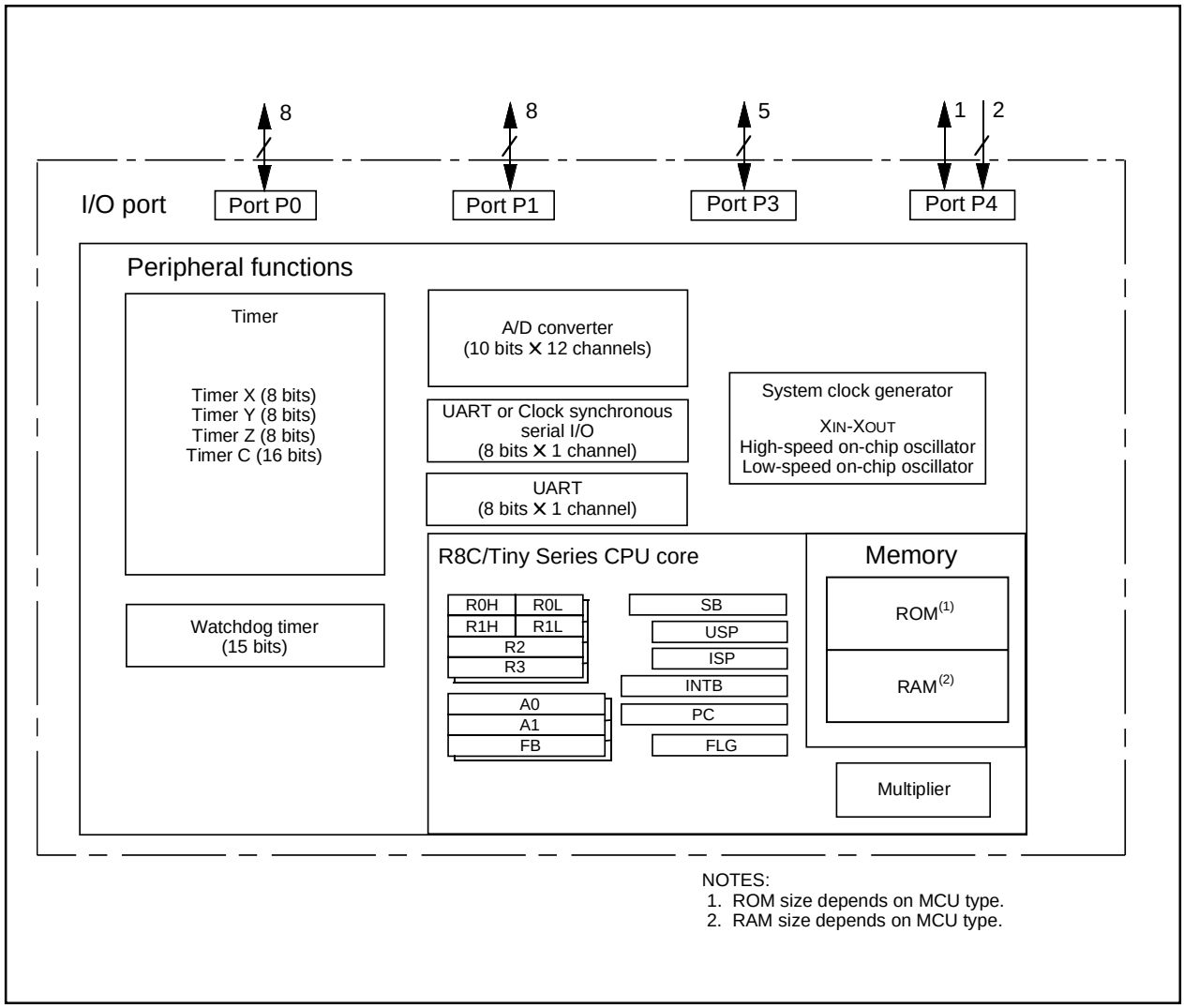


Figure 1.1 Block Diagram

1.4 Product Information

Table 1.2 lists the product information.

Table 1.2 Product Information

As of January 2006

Type No.	ROM capacity	RAM capacity	Package type	Remarks
R5F21112FP	8K bytes	512 bytes	PLQP0032GB-A	Flash memory version
R5F21113FP	12K bytes	768 bytes	PLQP0032GB-A	
R5F21114FP	16K bytes	1K bytes	PLQP0032GB-A	
R5F21112DFP	8K bytes	512 bytes	PLQP0032GB-A	D version
R5F21113DFP	12K bytes	768 bytes	PLQP0032GB-A	
R5F21114DFP	16K bytes	1K bytes	PLQP0032GB-A	

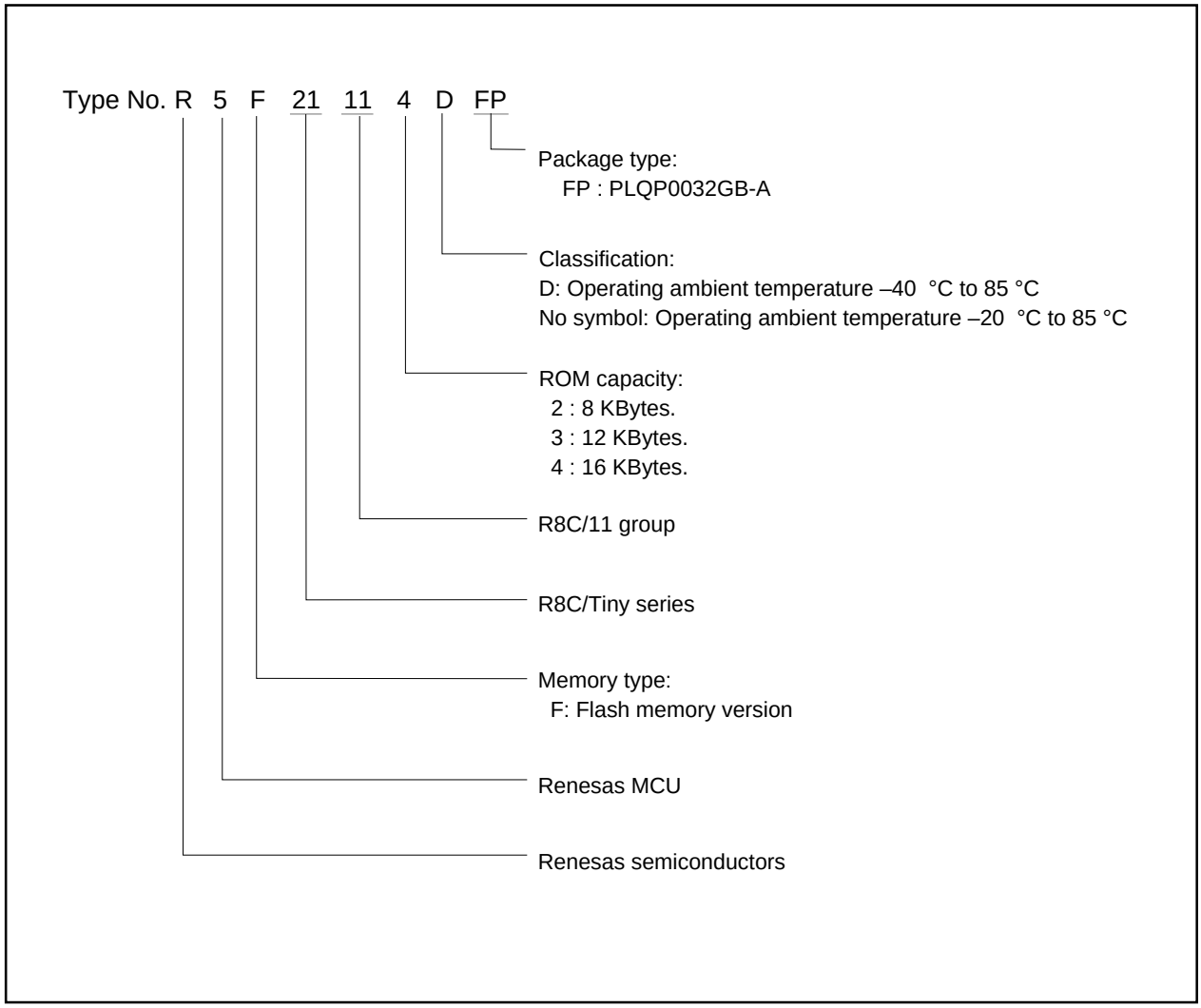


Figure 1.2 Type No., Memory Size, and Package

2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU registers. The CPU has 13 registers. Of these, R0, R1, R2, R3, A0, A1 and FB comprise a register bank. Two sets of register banks are provided.

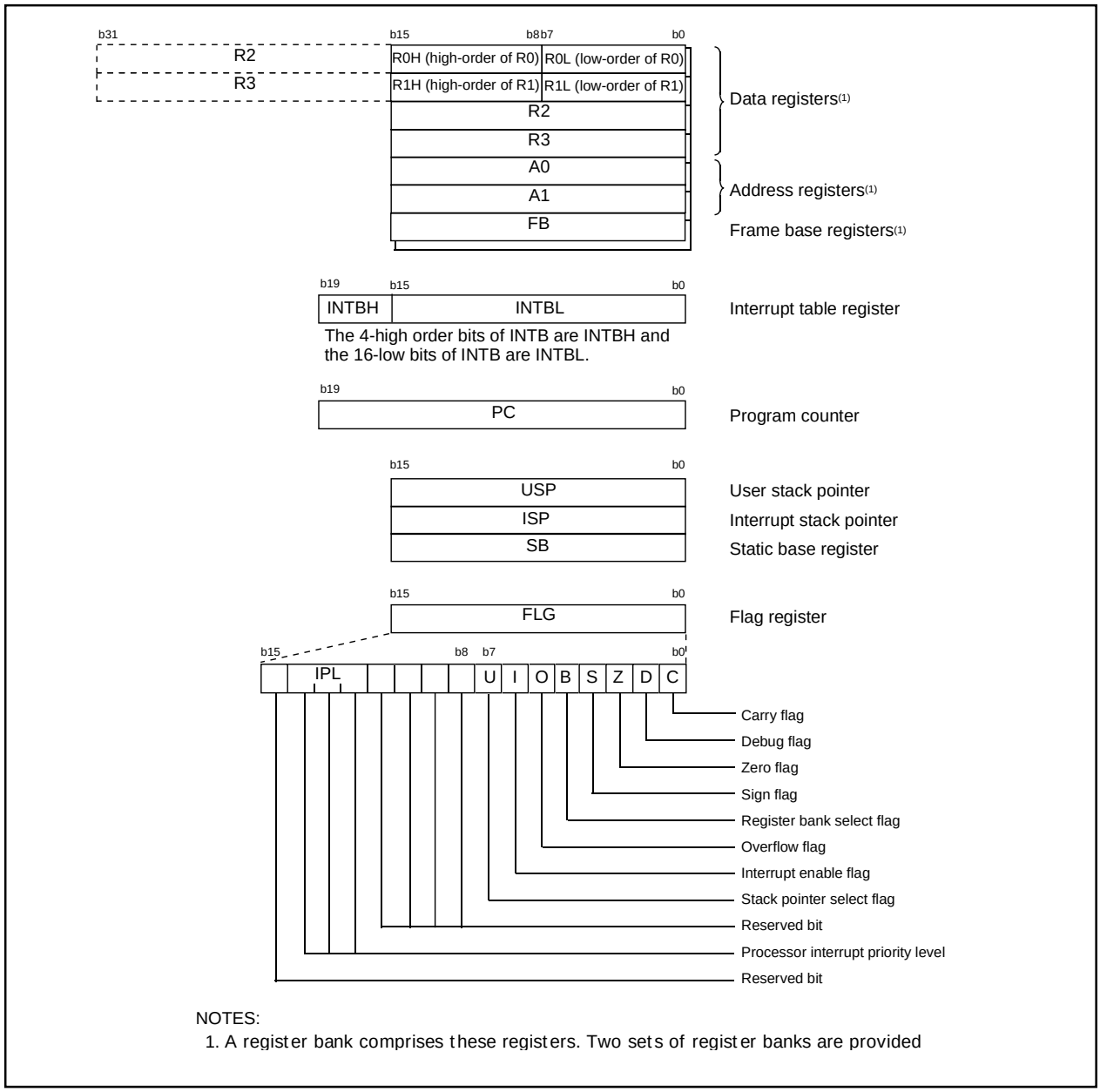


Figure 2.1 CPU Register

2.1 Data Registers (R0, R1, R2 and R3)

R0 is a 16-bit register for transfer, arithmetic and logic operations. The same applies to R1 to R3. The R0 can be split into high-order bit (R0H) and low-order bit (R0L) to be used separately as 8-bit data registers. The same applies to R1H and R1L as R0H and R0L. R2 can be combined with R0 to be used as a 32-bit data register (R2R0). The same applies to R3R1 as R2R0.

2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. They also are used for transfer, arithmetic and logic operations. The same applies to A1 as A0. A0 can be combined with A0 to be used as a 32-bit address register (A1A0).

2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

2.4 Interrupt Table Register (INTB)

INTB is a 20-bit register indicates the start address of an interrupt vector table.

2.5 Program Counter (PC)

PC, 20 bits wide, indicates the address of an instruction to be executed.

2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointer (SP), USP and ISP, are 16 bits wide each.

The U flag of FLG is used to switch between USP and ISP.

2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

2.8 Flag Register (FLG)

FLG is a 11-bit register indicating the CPU state.

2.8.1 Carry Flag (C)

The C flag retains a carry, borrow, or shift-out bit that has occurred in the arithmetic logic unit.

2.8.2 Debug Flag (D)

The D flag is for debug only. Set to “0”.

2.8.3 Zero Flag (Z)

The Z flag is set to “1” when an arithmetic operation resulted in 0; otherwise, “0”.

2.8.4 Sign Flag (S)

The S flag is set to “1” when an arithmetic operation resulted in a negative value; otherwise, “0”.

2.8.5 Register Bank Select Flag (B)

The register bank 0 is selected when the B flag is “0”. The register bank 1 is selected when this flag is set to “1”.

2.8.6 Overflow Flag (O)

The O flag is set to “1” when the operation resulted in an overflow; otherwise, “0”.

2.8.7 Interrupt Enable Flag (I)

The I flag enables a maskable interrupt.

An interrupt is disabled when the I flag is set to “0”, and are enabled when the I flag is set to “1”. The I flag is set to “0” when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to “0”, USP is selected when the U flag is set to “1”.

The U flag is set to “0” when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL, 3 bits wide, assigns processor interrupt priority levels from level 0 to level 7.

If a requested interrupt has greater priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

When write to this bit, set to “0”. When read, its content is indeterminate.

3. Memory

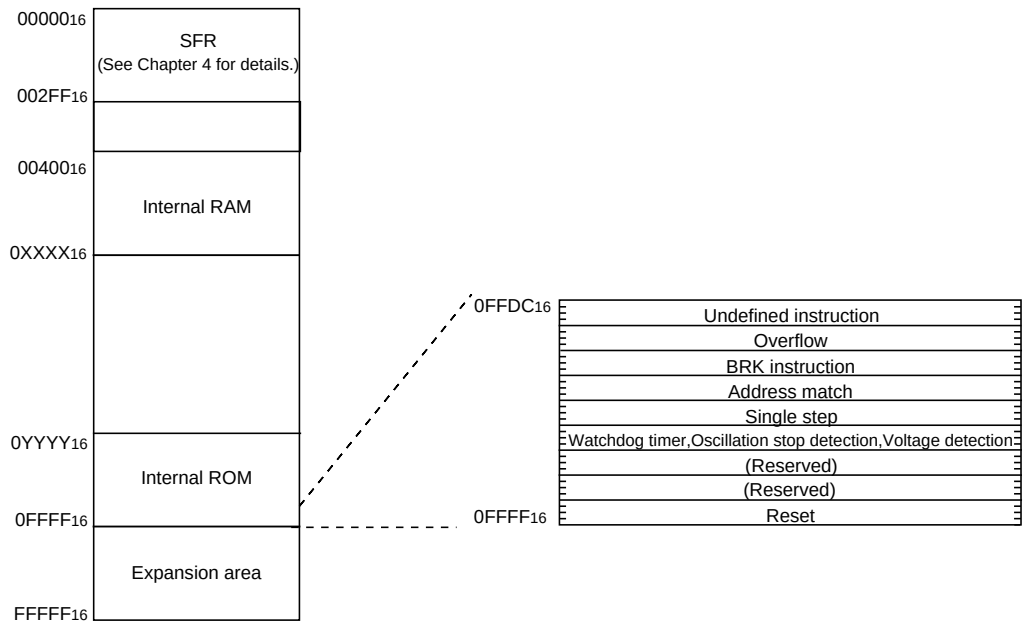
Figure 3.1 is a memory map of this MCU. This MCU provides 1-Mbyte address space from addresses 00000_{16} to $FFFFF_{16}$.

The internal ROM is allocated lower addresses beginning with address $0FFFF_{16}$. For example, a 16-Kbyte internal ROM is allocated addresses from $0C000_{16}$ to $0FFFF_{16}$.

The fixed interrupt vector table is allocated addresses $0FFDC_{16}$ to $0FFFF_{16}$. They store the starting address of each interrupt routine.

The internal RAM is allocated higher addresses beginning with address 00400_{16}. For example, a 1-Kbyte internal RAM is allocated addresses 00400_{16} to $007FF_{16}$. The internal RAM is used not only for storing data, but for calling subroutines and stacks when interrupt request is acknowledged.

Special function registers (SFR) are allocated addresses 00000_{16} to $002FF_{16}$. The peripheral function control registers are located them. All addresses, which have nothing allocated within the SFR, are reserved area and cannot be accessed by users.



NOTES :
1. Blank spaces are reserved. No access is allowed.

Type name	Internal ROM		Internal RAM	
	Size	Address 0YYYY₁₆	Size	Address 0XXXX₁₆
R5F21114FP, R5F21114DFP	16K bytes	0C000₁₆	1K bytes	007FF₁₆
R5F21113FP, R5F21113DFP	12K bytes	0D000₁₆	768 bytes	006FF₁₆
R5F21112FP, R5F21112DFP	8K bytes	0E000₁₆	512 bytes	005FF₁₆

Figure 3.1 Memory Map

Table 4.4 SFR Information(4)(1)

Address	Register	Symbol	After reset
00C0₁₆	AD register	AD	XX16
00C1₁₆			XX16
00C2₁₆			
00C3₁₆			
00C4₁₆			
00C5₁₆			
00C6₁₆			
00C7₁₆			
00C8₁₆			
00C9₁₆			
00CA₁₆			
00CB₁₆			
00CC₁₆			
00CD₁₆			
00CE₁₆			
00CF₁₆			
00D0₁₆			
00D1₁₆			
00D2₁₆			
00D3₁₆			
00D4₁₆	AD control register 2	ADCON2	0016
00D5₁₆			
00D6₁₆	AD control register 0	ADCON0	00000XXX2
00D7₁₆	AD control register 1	ADCON1	0016
00D8₁₆			
00D9₁₆			
00DA₁₆			
00DB₁₆			
00DC₁₆			
00DD₁₆			
00DE₁₆			
00DF₁₆			
00E0₁₆	Port P0 register	P0	XX16
00E1₁₆	Port P1 register	P1	XX16
00E2₁₆	Port P0 direction register	PD0	0016
00E3₁₆	Port P1 direction register	PD1	0016
00E4₁₆			
00E5₁₆	Port P3 register	P3	XX16
00E6₁₆			
00E7₁₆	Port P3 direction register	PD3	0016
00E8₁₆	Port P4 register	P4	XX16
00E9₁₆			
00EA₁₆	Port P4 direction register	PD4	0016
00EB₁₆			
00EC₁₆			
00ED₁₆			
00EE₁₆			
00EF₁₆			
00F0₁₆			
00F1₁₆			
00F2₁₆			
00F3₁₆			
00F4₁₆			
00F5₁₆			
00F6₁₆			
00F7₁₆			
00F8₁₆			
00F9₁₆			
03FA₁₆			
00FB₁₆			
00FC₁₆	Pull-up control register 0	PUR0	00XX00002
00FD₁₆	Pull-up control register 1	PUR1	XXXXXX0X2
00FE₁₆	Port P1 drive capacity control register	DRR	0016
00FF₁₆	Timer C output control register	TCOUT	0016
≈			≈
01B3₁₆	Flash memory control register 4	FMR4	010000002
01B4₁₆			
01B5₁₆	Flash memory control register 1	FMR1	0100XX0X2
01B6₁₆			
01B7₁₆	Flash memory control register 0	FMR0	000000012

X : Undefined
NOTES:
1. Blank columns, 0100₁₆ to 01B2₁₆ and 01B8₁₆ to 02FF₁₆ are all reserved. No access is allowed.

5. Electrical Characteristics

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated value	Unit
V_{CC}	Supply voltage	V_{CC}=AV$_{CC}$	-0.3 to 6.5	V
AV$_{CC}$	Analog supply voltage	V_{CC}=AV$_{CC}$	-0.3 to 6.5	V
V_I	Input voltage		-0.3 to V_{CC}+0.3	V
V_O	Output voltage		-0.3 to V_{CC}+0.3	V
P_d	Power dissipation	Topr=25 °C	300	mW
T_{opr}	Operating ambient temperature		-20 to 85 / -40 to 85 (D version)	°C
T_{stg}	Storage temperature		-65 to 150	°C

Table 5.2 Recommended Operating Conditions

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
V_{CC}	Supply voltage			2.7	—	5.5	V
AVcc	Analog supply voltage			—	V_{CC}(3)	—	V
Vss	Supply voltage			—	0	—	V
AVss	Analog supply voltage			—	0	—	V
V_{IH}	"H" input voltage			0.8V_{CC}	—	V_{CC}	V
V_{IL}	"L" input voltage			0	—	0.2V_{CC}	V
$I_{OH (sum)}$	"H" peak all output currents	Sum of all pins' IOH (peak)		—	—	-60.0	mA
$I_{OH (peak)}$	"H" peak output current			—	—	-10.0	mA
$I_{OH (avg)}$	"H" average output current			—	—	-5.0	mA
$I_{OL (sum)}$	"L" peak all output currents	Sum of all pins' IOL (peak)		—	—	60	mA
$I_{OL (peak)}$	"L" peak output current	Except P1$_0$ to P1$_7$		—	—	10	mA
		P1$_0$ to P1$_7$	Drive capacity HIGH	—	—	30	mA
			Drive capacity LOW	—	—	10	mA
$I_{OL (avg)}$	"L" average output current	Except P1$_0$ to P1$_7$		—	—	5	mA
		P1$_0$ to P1$_7$	Drive capacity HIGH	—	—	15	mA
			Drive capacity LOW	—	—	5	mA
f (X_{IN})	Main clock input oscillation frequency		3.0V ≤ Vcc ≤ 5.5V	0	—	20	MHz
			2.7V ≤ Vcc < 3.0V	0	—	10	MHz

NOTES:
1. V_{CC} = AV$_{CC}$ = 2.7 to 5.5V at Topr = -20 to 85 °C / -40 to 85 °C, unless otherwise specified.
2. The typical values when average output current is 100ms.
3. Hold Vcc=AVcc.

Table 5.3 A/D Conversion Characteristics

Symbol	Parameter		Measuring condition	Standard			Unit
				Min.	Typ.	Max.	
–	Resolution		V_{ref} =V_{CC}	—	—	10	Bit
–	Absolute accuracy	10 bit mode	øAD=10 MHz, Vref=Vcc=5.0V	—	—	±3	LSB
		8 bit mode	øAD=10 MHz, Vref=Vcc=5.0V	—	—	±2	LSB
		10 bit mode	øAD=10 MHz, Vref=Vcc=3.3V(3)	—	—	±5	LSB
		8 bit mode	øAD=10 MHz, Vref=Vcc=3.3V(3)		—	±2	LSB
R_{LADDER}	Ladder resistance		V_{REF}=V_{CC}	10	—	40	kΩ
t_{CONV}	Conversion time	10 bit mode	øAD=10 MHz, Vref=Vcc=5.0V	3.3	—	—	µs
		8 bit mode	øAD=10 MHz, Vref=Vcc=5.0V	2.8	—	—	µs
V_{REF}	Reference voltage			—	V_{CC}(4)	—	V
V_{IA}	Analog input voltage			0	—	V_{ref}	V
–	A/D operating clock frequency(2)	Without sample & hold		0.25	—	10	MHz
		With sample & hold		1.0	—	10	MHz

NOTES:
1. V_{CC}=AV_{CC}=2.7 to 5.5V at Topr = -20 to 85 °C / -40 to 85 °C, unless otherwise specified.
2. If f_{AD} exceeds 10 MHz more, divide the f_{AD} and hold A/D operating clock frequency (Ø$_{AD}$) 10 MHz or below.
3. If the AVcc is less than 4.2V, divide the f_{AD} and hold A/D operating clock frequency (Ø$_{AD}$) f_{AD}/2 or below.
4. Hold Vcc=Vref.

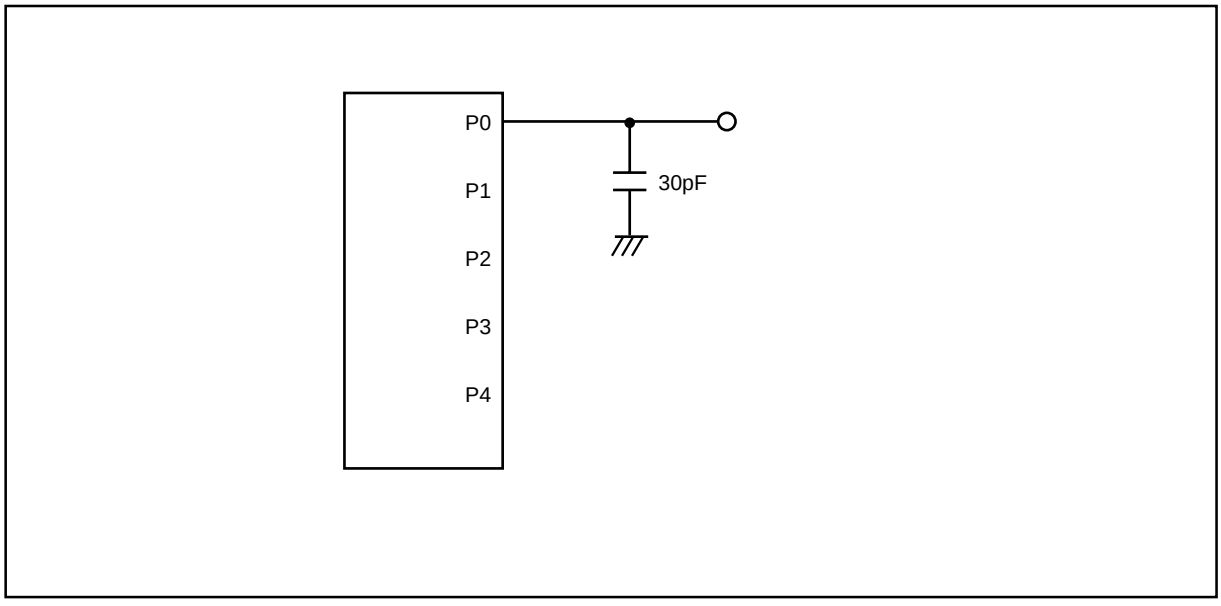


Figure 5.1 Port P0 to P4 measurement circuit

Table 5.4 Flash Memory Version Electrical Characteristics

Symbol	Parameter	Measuring condition	Standard			Unit
			Min.	Typ.	Max	
–	Program/erase endurance		100	—	—	times
–	Byte program time		—	50	400	µs
–	Block erase time		—	0.4	9	s
td(SR-ES)	Time delay from suspend request until erase suspend		—	—	8	ms
–	Erase Suspend Request Interval		10	—	—	ms
–	Program, Erase voltage		2.7	—	5.5	V
–	Read voltage		2.7	—	5.5	V
–	Program, Erase temperature		0	—	60	°C
–	Data hold time(2)	Ambient temperature=55 °C	20	—	—	year

NOTES:
1. Referenced to V_{CC1}=AVcc=2.7 to 5.5V at Topr = 0 to 60 °C unless otherwise specified.
2. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.5 Voltage Detection Circuit Electrical Characteristics

Symbol	Parameter	Measuring condition	Standard			Unit
			Min.	Typ.	Max.	
Vdet	Voltage detection level		3.3	3.8	4.3	V
—	Voltage detection interrupt request generating time(2)		—	40	—	µs
—	Voltage detection circuit self consumption current	VC27=1, VCC=5.0V	—	600	—	nA
td(E-A)	Waiting time till voltage detection circuit operation starts(3)		—	—	20	µs
Vccmin	Minimum value of microcomputer operation voltage		2.7	—	—	V

NOTES:
1. The measuring condition is Vcc=AVcc=2.7V to 5.5V and Topr= -40°C to 85 °C.
2. This shows the time until the voltage detection interrupt request is generated since the voltage passes Vdet.
3. This shows the required time until the voltage detection circuit operates when setting to "1" again after setting the VC27 bit in the VCR2 register to “0”.

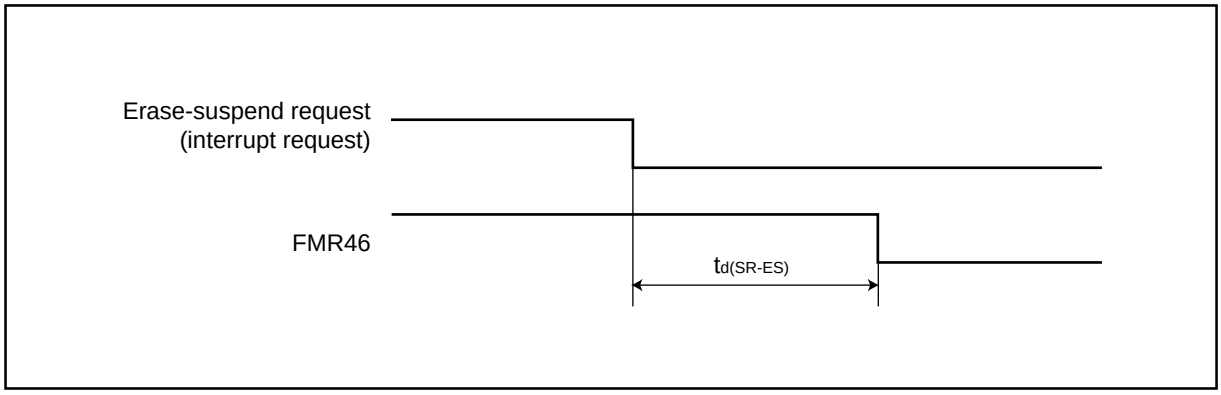


Figure 5.2 Time delay from Suspend Request until Erase Suspend

Timing requirements (Unless otherwise noted: VCC = 5V, VSS = 0V at Topr = 25 °C) [VCC=5V]

Table 5.12 XIN input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tc(XIN)	XIN input cycle time	50	–	ns
twH(XIN)	XIN input HIGH pulse width	25	–	ns
twL(XIN)	XIN input LOW pulse width	25	–	ns

Table 5.13 CNTR0 input, CNTR1 input, $\overline{\text{INT2}}$ input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tc(CNTR0)	CNTR0 input cycle time	100	–	ns
twH(CNTR0)	CNTR0 input HIGH pulse width	40	–	ns
twL(CNTR0)	CNTR0 input LOW pulse width	40	–	ns

Table 5.14 TCIN input, $\overline{\text{INT3}}$ input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tc(TCIN)	TCIN input cycle time	400(1)	–	ns
twH(TCIN)	TCIN input HIGH pulse width	200(2)	–	ns
twL(TCIN)	TCIN input LOW pulse width	200(2)	–	ns

NOTES:
1. When using the Timer C input capture mode, adjust the cycle time above (1/ Timer C count source frequency x 3).
2. When using the Timer C input capture mode, adjust the pulse width above (1/ Timer C count source frequency x 1.5).

Table 5.15 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tc(CK)	CLKi input cycle time	200	–	ns
tw(CKH)	CLKi input HIGH pulse width	100	–	ns
tw(CKL)	CLKi input LOW pulse width	100	–	ns
td(C-Q)	TxDi output delay time	–	80	ns
th(C-Q)	TxDi hold time	0	–	ns
tsu(D-C)	RxDi input setup time	35	–	ns
th(C-D)	RxDi input hold time	90	–	ns

Table 5.16 External interrupt $\overline{\text{INT0}}$ input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tw(INH)	$\overline{\text{INT0}}$ input HIGH pulse width	250(1)	–	ns
tw(INL)	$\overline{\text{INT0}}$ input LOW pulse width	250(2)	–	ns

NOTES:
1. When selecting the digital filter by the $\overline{\text{INT0}}$ input filter select bit, use the $\overline{\text{INT0}}$ input HIGH pulse width to the greater value,either (1/ digital filter clock frequency x 3) or the minimum value of standard.
2. When selecting the digital filter by the $\overline{\text{INT0}}$ input filter select bit, use the $\overline{\text{INT0}}$ input LOW pusle width to the greater value,either (1/ digital filter clock frequency x 3) or the minimum value of standard.

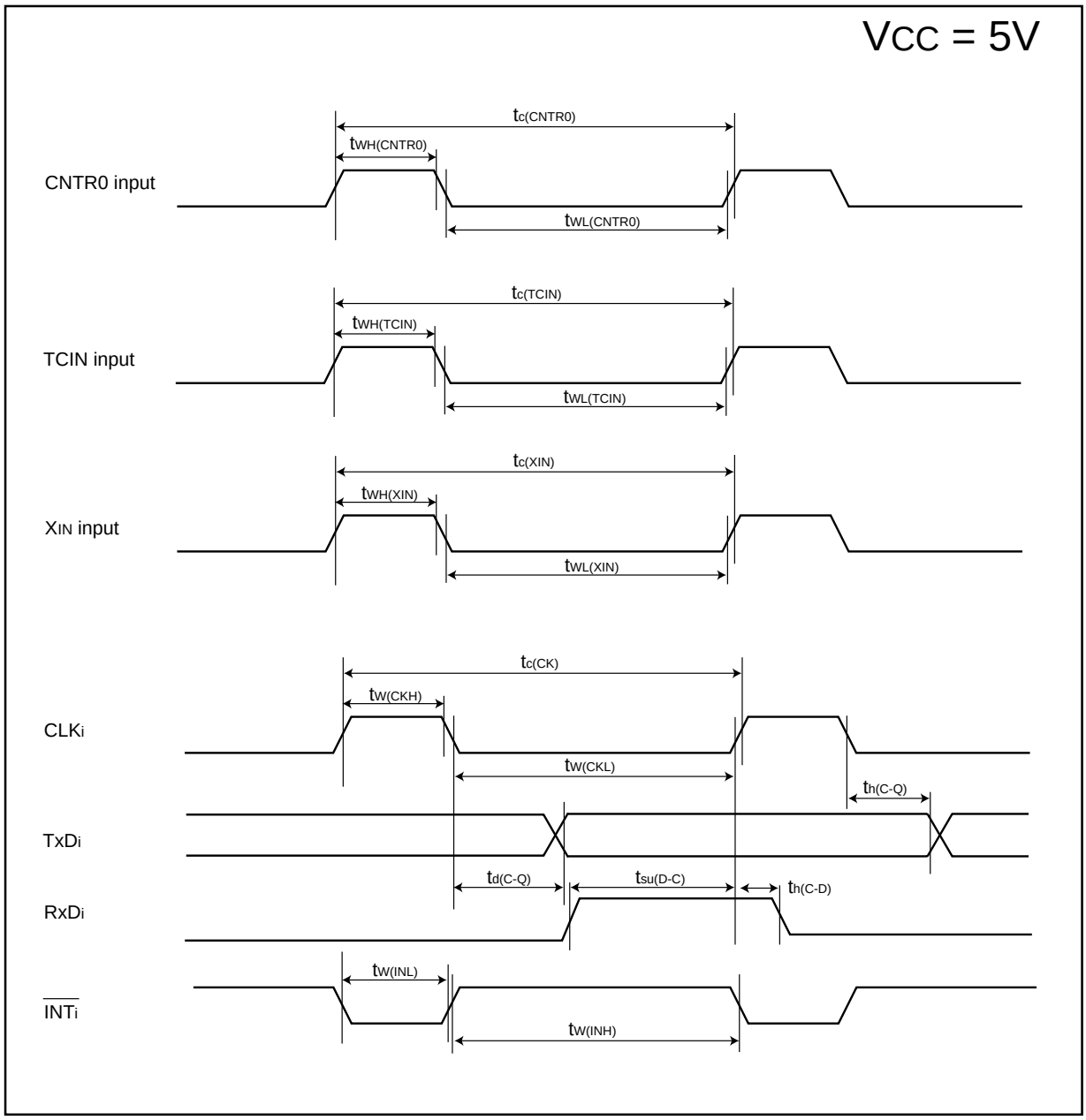


Figure 5.4 Vcc=5V timing diagram

Table 5.17 Electrical Characteristics (3) [Vcc=3V]

Symbol	Parameter		Measuring condition		Standard			Unit
					Min.	Typ.	Max.	
V_{OH}	"H" output voltage	Except X_{OUT}	I_{OH}=-1mA		V_{CC}-0.5	—	V_{CC}	V
		X_{OUT}	Drive capacity HIGH	I_{OH}=-0.1 mA	V_{CC}-0.5	—	V_{CC}	V
			Drive capacity LOW	I_{OH}=-50 µA	V_{CC}-0.5	—	V_{CC}	V
V_{OL}	"L" output voltage	Except P10 to P17, X_{OUT}	I_{OL}= 1 mA		—	—	0.5	V
		P10 to P17	Drive capacity HIGH	I_{OL}= 2 mA	—	—	0.5	V
			Drive capacity LOW	I_{OL}= 1 mA	—	—	0.5	V
		X_{OUT}	Drive capacity HIGH	I_{OL}= 0.1 mA	—	—	0.5	V
			Drive capacity LOW	I_{OL}=50 µA	—	—	0.5	V
V_{T+}-V_{T-}	Hysteresis	$\overline{INT0}$, $\overline{INT1}$, $\overline{INT2}$, $\overline{INT3}$, $\overline{KI0}$, $\overline{KI1}$, $\overline{KI2}$, KI3, CNTR0, CNTR1, TCIN, RxD0, RxD1, P45			0.2	—	0.8	V
		$\overline{RESET}$			0.2	—	1.8	V
I_{IH}	"H" input current		V_I=3V		—	—	4.0	µA
I_{IL}	"L" input current		V_I=0V		—	—	-4.0	µA
R_{PULLUP}	Pull-up resistance		V_I=0V		66	160	500	kΩ
R_{fXIN}	Feedback resistance	X_{IN}			—	3.0	—	MΩ
f_{RING-S}	Low-speed on-chip oscillator frequency				40	125	250	kHz
V_{RAM}	RAM retention voltage		At stop mode		2.0	—	—	V

NOTES:
1. Referenced to V_{CC} = AV_{CC} = 2.7 to 3.3V at Topr = -20 to 85 °C / -40 to 85 °C, f(X_{IN})=10MHz unless otherwise specified.

Table 5.18 Electrical Characteristics (4) [Vcc=3V]

Symbol	Parameter	Measuring condition		Standard			Unit
				Min.	Typ.	Max.	
I_{CC}	Power supply current (V_{CC}=2.7 to 3.3V) In single-chip mode, the output pins are open and other pins are V_{SS}	High-speed mode	X_{IN}=20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz No division	—	8	13	mA
			X_{IN}=16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz No division	—	7	12	mA
			X_{IN}=10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz No division	—	5	—	mA
		Medium-speed mode	X_{IN}=20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz Division by 8	—	3	—	mA
			X_{IN}=16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz Division by 8	—	2.5	—	mA
			X_{IN}=10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz Division by 8	—	1.6	—	mA
		High-speed on-chip oscillator mode	Main clock off High-speed on-chip oscillator on=8 MHz Low-speed on-chip oscillator on=125 kHz No division	—	3.5	7.5	mA
			Main clock off High-speed on-chip oscillator on=8 MHz Low-speed on-chip oscillator on=125 kHz Division by 8	—	1.5	—	mA
		Low-speed on-chip oscillator mode	Main clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz Division by 8	—	420	800	µA
		Wait mode	Main clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz When a WAIT instruction is executed(1) Peripheral clock operation VC27="0"	—	37	74	µA
		Wait mode	Main clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on=125 kHz When a WAIT instruction is executed(1) Peripheral clock off VC27="0"	—	35	70	µA
		Stop mode	Main clock off, Topr = 25 °C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10="1" Peripheral clock off VC27="0"	—	0.7	3.0	µA

NOTES:
1. Timer Y is operated with timer mode.
2. Referenced to V_{CC} = AV_{CC} = 2.7 to 3.3V at Topr = -20 to 85 °C / -40 to 85 °C, f(X_{IN})=10MHz unless otherwise specified.

Timing requirements (Unless otherwise noted: VCC = 3V, VSS = 0V at Topr = 25 °C) [VCC=3V]

Table 5.19 XIN input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tC(XIN)	XIN input cycle time	100	–	ns
tWH(XIN)	XIN input HIGH pulse width	40	–	ns
tWL(XIN)	XIN input LOW pulse width	40	–	ns

Table 5.20 CNTR0 input, CNTR1 input, $\overline{\text{INT2}}$ input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tC(CNTR0)	CNTR0 input cycle time	300	–	ns
tWH(CNTR0)	CNTR0 input HIGH pulse width	120	–	ns
tWL(CNTR0)	CNTR0 input LOW pulse width	120	–	ns

Table 5.21 TCIN input, $\overline{\text{INT3}}$ input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tC(TCIN)	TCIN input cycle time	1200(1)	–	ns
tWH(TCIN)	TCIN input HIGH pulse width	600(2)	–	ns
tWL(TCIN)	TCIN input LOW pulse width	600(2)	–	ns

NOTES:
1. When using the Timer C input capture mode, adjust the cycle time above (1/ Timer C count source frequency x 3).
2. When using the Timer C input capture mode, adjust the pulse width above (1/ Timer C count source frequency x 1.5).

Table 5.22 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tC(CK)	CLKi input cycle time	300	–	ns
tW(CKH)	CLKi input HIGH pulse width	150	–	ns
tW(CKL)	CLKi input LOW pulse width	150	–	ns
td(C-Q)	TxDi output delay time	–	160	ns
th(C-Q)	TxDi hold time	0	–	ns
tsu(D-C)	RxDi input setup time	55	–	ns
th(C-D)	RxDi input hold time	90	–	ns

Table 5.23 External interrupt $\overline{\text{INT0}}$ input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
tW(INH)	$\overline{\text{INT0}}$ input HIGH pulse width	380(1)	–	ns
tW(INL)	$\overline{\text{INT0}}$ input LOW pulse width	380(2)	–	ns

NOTES:
1. When selecting the digital filter by the $\overline{\text{INT0}}$ input filter select bit, use the $\overline{\text{INT0}}$ input HIGH pulse width to the greater value,either (1/ digital filter clock frequency x 3) or the minimum value of standard.
2. When selecting the digital filter by the $\overline{\text{INT0}}$ input filter select bit, use the $\overline{\text{INT0}}$ input LOW pusle width to the greater value,either (1/ digital filter clock frequency x 3) or the minimum value of standard.

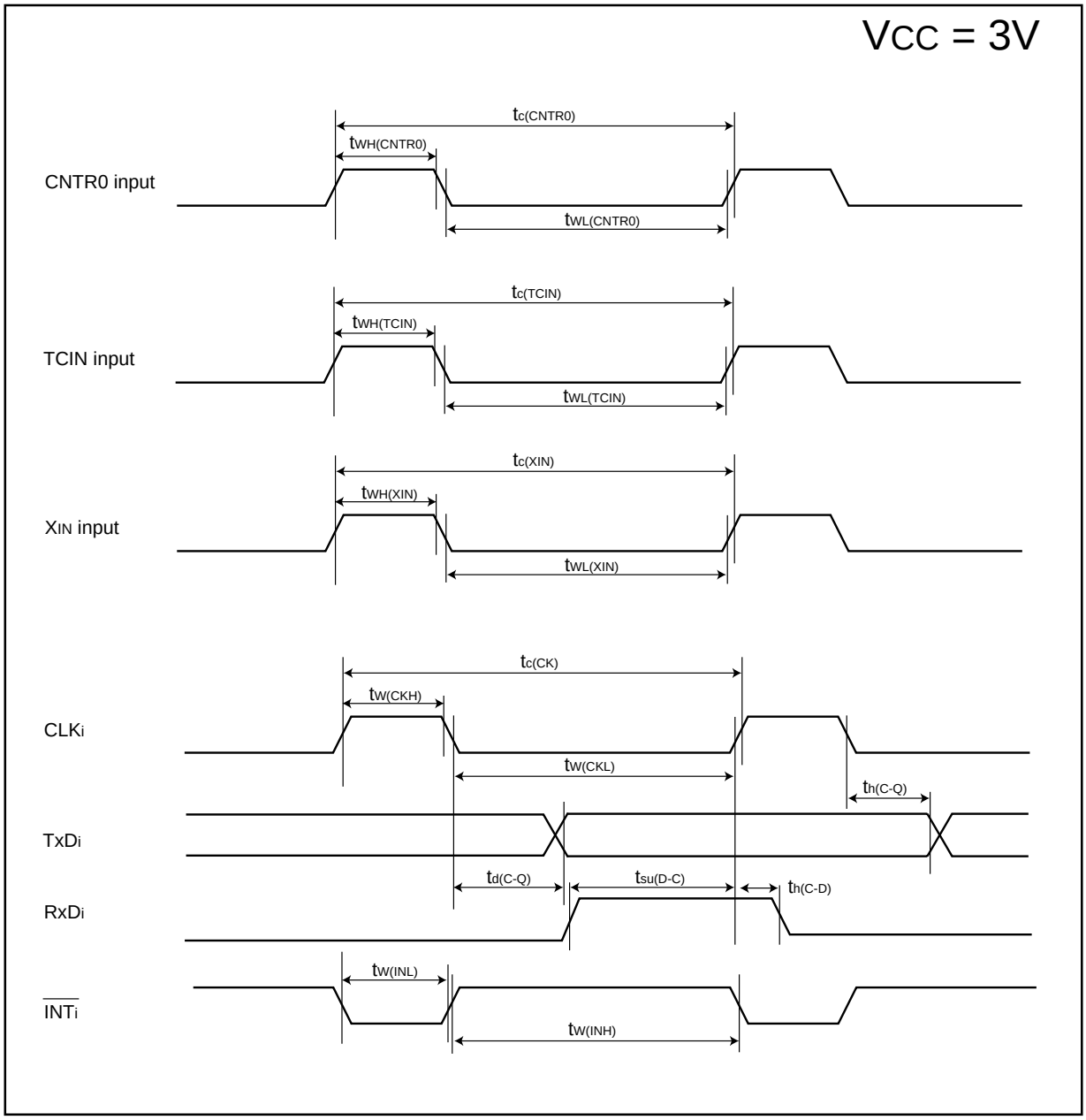
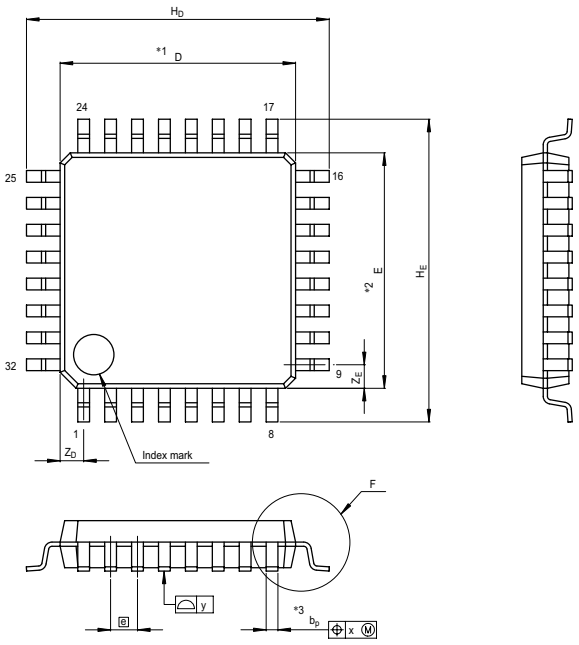
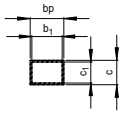


Figure 5.5 Vcc=3V timing diagram

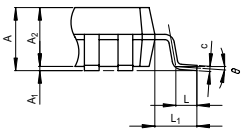
Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-LQFP32-7x7-0.80	PLQP0032GB-A	32P6U-A	0.2g





Terminal cross section



Detail F

NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	6.9	7.0	7.1
E	6.9	7.0	7.1
A_2	—	1.4	—
H_D	8.8	9.0	9.2
H_E	8.8	9.0	9.2
A	—	—	1.7
A_1	0	0.1	0.2
b_p	0.32	0.37	0.42
b_1	—	0.35	—
c	0.09	0.145	0.20
c_1	—	0.125	—
θ	0°	—	8°
e	—	0.8	—
x	—	—	0.20
y	—	—	0.10
Z_D	—	0.7	—
Z_E	—	0.7	—
L	0.3	0.5	0.7
L_1	—	1.0	—

REVISION HISTORY	R8C/11 Group Datasheet

Rev.	Date	Description	
		Page	Summary
1.00	Jun. 19, 2003		First edition issued
1.10	Sep. 08, 2003	2	Table 1.1: Shortest instruction execution time and f(XIN) changed
		5	Figure 1.3: Pin name changed from TXOUT to $\overline{\text{CNTR0}}$
		6	Table 1.3: Pin name changed from TXOUT to $\overline{\text{CNTR0}}$
		10	The value of HR1 register after reset changed
		12	The value of TC register after reset changed
		14	Chapter “5. Electrical Characteristics” added
1.20	Oct. 31, 2003	2	Table 1.1: Power consumption values added
		6	Table 1.3: Resistor value for CNVss and MODE deleted
		11	Register name of address 0050_{16} modified from CMP2IC to CMP1IC, register name of address $005C_{16}$ modified from CMP1IC to CMP0IC
		14	Table 5.2: Note 3 and Note 4 deleted
		15	tsamp in Table 5.3 deleted
		17	Figure 5.1 added
		19	Table 5.10: Vcc changed from “4.2 to 5.5V” to “3.3V to 5.5V”, low-power on-chip oscillator changed from “on 100kHz” to “125kHz”, XIN=5MHz deleted and XIN=10MHz added in high-speed mode and medium-speed mode, VC27=”0” added in stop mode measuring condition, data added and modified
		20	Table 11 to Table 15 added
		21	Figure 5.2 added
		22	Table 5.16: Note 1, f(BCLK)=5 MHz changed to 10 MHz
		23	Table 5.17: low-power ring oscillator changed from “on 100kHz” to “125kHz”, XIN=5MHz deleted and XIN=10MHz added in high-speed mode and medium-speed mode, VC27=”0” added in stop mode measuring condition, data added and modified
		24	Table 5.18 to Table 5.22 added
		25	Figure 5.3 added
1.30	Dec 05, 2003	4	Table 1.2 : ** deleted
		15	Table 5.4 revised
1.40	Sep 30, 2004	all pages	Words standardized (on-chip oscillator, serial interface, A/D)
		2	Table 1.1 revised
		5	Figure 1.3, NOTES 3 added
		6	Table 1.3 revised
		9	Figure 3.1, NOTES added
		10-13	One body sentence in chapter 4 added ; Title of Table 4.1 to 4.4 added
		12	Table 4.3 revised ; Table 4.4 revised
		14	Table 5.2 revised
		15	Table 5.3 revised
		16	Table 5.4 revised ; Table 16.5 revised
		17	Table 5.6, 5.7 adn 5.8 revised ; Figure 5.3 revised
		18	Table 5.9 revised ; Table 5.10 revised

Rev.	Date	Description	
		Page	Summary
1.40	Sep 30, 2004	20	Table 5.12 revised ; Table 5.16 revised
		22	Table 16.17 revised
		24	Table 16.19 revised
1.50	Apr.27.2005	4	Table 1.2, Figure 1.2 package name revised
		5	Figure 1.3 package name revised
		10	Table 4.1 revised
		12	Table 4.3 revised
		15	Table 5.3 partly revised
		16	Table 5.4 partly added
		17	Table 5.6, Table 5.7 revised
		18	Table 5.9, Table 10 partly revised
		22	Table 5.17 partly revised
		26	Package Dimensions revised
1.60	Jan.27.2006	2	Table 1.1 Performance outline revised
		3	Figure 1.1 Block diagram partly revised
		4	1.4 Product Information, title of Table 1.2 “Product List” → “Product Informaton” revised Figure 1.2 Type No., Memory Size, and Package partly revised
		6	Table 1.3 Pin description revised
		7-8	2 Central Processing Unit (CPU) revised Figure 2.1 CPU register revised
		10	Table 4.1 SFR Information(1) NOTES:1 revised
		11	Table 4.2 SFR Information(2) NOTES:1 revised
		12	Table 4.3 SFR Information(3); 0081_{16}: “Prescaler Y” → “Prescaler Y Register” 0082_{16}: “Timer Y Secondary” → “Timer Y Secondary Register” 0083_{16}: “Timer Y Primary” → “Timer Y Primary Register” 0085_{16}: “Prescaler Z” → “Prescaler Z Register” 0086_{16}: “Timer Z Secondary” → “Timer Z Secondary Register” 0087_{16}: “Timer Z Primary” → “Timer Z Primary Register” $008C_{16}$: “Prescaler X” → “Prescaler X Register” revised NOTES:1, 2 revised
		13	Table 4.4 SFR Information(4) NOTES:1 revised
		14	Table 5.2 Recommended Operating Conditions; NOTES: 1, 2, 3 revised
		15	Table 5.3 A/D Conversion Characteristics; “A/D operation clock frequency” → “A/D operating clock frequency” revised NOTES: 1, 2, 3, 4 revised
		16	Table 5.4 Flash Memory (Program ROM) Electrical Characteristics; “Topr” → “Ambient temperature” revised Measuring condition of byte program time and block erase time deleted
		17	Table 5.6 Reset Circuit Electrical Characteristics (When Using Hardware Reset 2) NOTES: 3 revised
		18	Table 5.8 High-speed On-Chip Oscillator Circuit Electrical Characteristics; “High-speed on-chip oscillator temperature dependence” → “High-speed on-chip oscillator frequency temperature dependence” revised Table 5.10 Electrical Characteristics (1) [V_{CC}=5V]; “$P1_0$ to $P1_7$ Except X_{OUT}” → “Except $P1_0$ to $P1_7$, X_{OUT}” revised

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